

## **UNITRODE**

## Octal Line Driver

## **FEATURES**

- Eight Single-Ended Line Drivers in One Package
- Meets Standards EIA232E/CCITT V.28, and EIA423A/CCITT V.10/X.26
- Single External Resistor Controls Slew Rate
- Wide Supply Voltage Range
- Tri-State Outputs
- Output Short-Circuit Protection
- Low Power Consumption
- 2kV ESD Protection on all Pins
- EOS on all Output Pins 35V under all Output Conditions
- High Current Output for Long Line Drive, Exceeds Standards

## **DESCRIPTION**

The UC5172 is a single-ended octal line driver designed to meet both standard modem control applications (EIA232E/V.28), and long line drive applications (EIA423A/V.10/X.26). The slew rate for all 8 drivers is controlled by a single external resistor. The slew rate and output levels are independent of the power variations.

The UC5172 has high output current, and current balance for long line drive applications. EOS - Output parasitic SCRs powered on and off are 35V, well above signal levels, allowing protection devices to work.

Inputs are compatible TTL+MOS logic families and are diode protected against negative transients.

### **FUNCTIONAL TABLE**

| INPUTS |      | OUTPUT          |  |  |  |  |
|--------|------|-----------------|--|--|--|--|
| EN     | DATA | EIA232E/EIA423A |  |  |  |  |
| 0      | 0    | 5V to 6V        |  |  |  |  |
| 0      | 1    | -5V to -6V      |  |  |  |  |
| 1      | X    | High Z          |  |  |  |  |

Note 2: Minimum output swings.

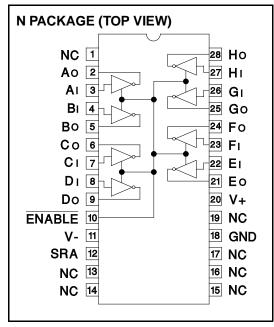
## **ABSOLUTE MAXIMUM RATINGS** (Note 1)

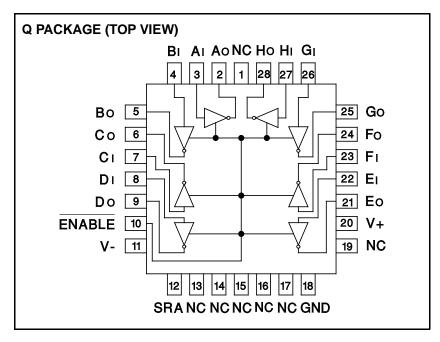
| V+ (Pin 20)                              |
|--|
| V- (Pin 11)                              |
| PLCC Power Dissipation, Ta=25°C (Note 3) |
| DIP Power Dissipation, Ta=25°C (Note 3)  |
| Input Voltage1.5V to +7V                 |
| Output Voltage6V to +6V                  |
| Slew Rate Resistor                       |
| Storage Temperature65°C to +150°C        |

Note 1: All voltages are with respect to ground, pin 18.

Note 3: Consult Packaging section of Databook for thermal limitations and considerations of package.

## **CONNECTION DIAGRAMS**





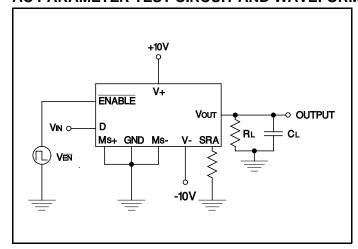
# **DC ELECTRICAL CHARACTERISTICS:** Unless otherwise stated these specifications hold for |V+| = |V-| = 10V, $0^{\circ}C < TA < +70^{\circ}C$ , RSRA = +10k, TA =TJ.

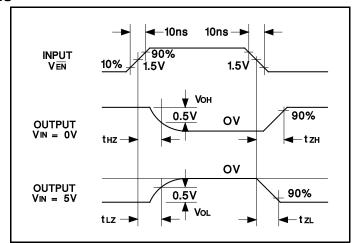
| PARAMETER                 | SYMBOL          | TE                     | ST CONDITIONS              | MIN  | TYP  | MAX  | UNITS |
|---------------------------|-----------------|------------------------|----------------------------|------|------|------|-------|
| POWER SUPPLY REQUIREMENTS |                 |                        |                            |      |      |      |       |
| V+ Range                  |                 |                        |                            | 9    |      | 15   | V     |
| V- Range                  |                 |                        |                            | 9    |      | -15  | V     |
| V+ Supply Current         | l+              | RL = Infinite E        | <u>in</u> = 0V             |      | 15   | 25   | mA    |
| V- Supply Current         | I-              | RL = Infinite E        | <u>n</u> = 0V              |      | -17  | -25  | mA    |
| INPUTS                    |                 |                        |                            |      |      |      |       |
| High-Level Input Voltage  | V <sub>IH</sub> |                        |                            | 2.0  |      |      | V     |
| Low-Level Input Voltage   | VIL             |                        |                            |      |      | 0.8  | V     |
| Input Clamp Voltage       | Vık             | Iı = -15 mA            |                            |      | -1.1 | -18  | V     |
| High Level Input Current  | Іін             | VIH = 2.4V             |                            | -2   | 0.25 | 40   | μΑ    |
| Low Level Input Current   | lı∟             | VIL = 0.4V             |                            | -200 | -8.0 |      | μΑ    |
| OUTPUTS                   |                 |                        |                            |      |      |      |       |
| High Level Output Voltage | Voн             | VIN = 0.8V             | RL = Inf.                  | 5.0  | 5.3  | 6.0  | V     |
| EIA232E                   |                 | $\overline{En} = 0.8V$ | RL = 3k                    | 5.0  | 5.3  | 6.0  | V     |
| (EIA-423A)                |                 |                        | RL = 450                   | 4.5  | 5.2  | 6.0  | V     |
| Low Level Output Voltage  | Vol             | VIN = 2.0V             | RL = Inf.                  | -5.0 | -5.3 | -6.0 | V     |
| EIA232E                   |                 | $\overline{En} = 0.8V$ | RL = 3k                    | -5.0 | -5.6 | -6.0 | V     |
| (EIA-423A)                |                 |                        | RL = 450                   | -4.5 | -5.4 | -6.0 | V     |
| Output Balance (EIA-423A) | VBAL            | RL = 450, VOH          | H - VOL = VBAL             |      | 0.2  | 0.4  | V     |
| Off-State Output Current  | loz             | En = 2.0V, Vo          | = ±6V, V+ = 15V, V- = -15V | -100 |      | 100  | μΑ    |
| Short-Circuit Current     | los             | En = 0V                | VIN = 0V                   | 25   | 65   |      | mA    |
|                           |                 |                        | VIN = 5V                   | 25   | 70   |      | mA    |
| Power Off Output Current  | IРО             | Vo = ±6V, V+           | = V- = 0V                  | -100 |      | 100  | mA    |

## **AC ELECTRICAL CHARACTERISTICS:** at |V+| = |V-| = +10V, $0^{\circ}C < TA < +70^{\circ}C$ , TA = TJ.

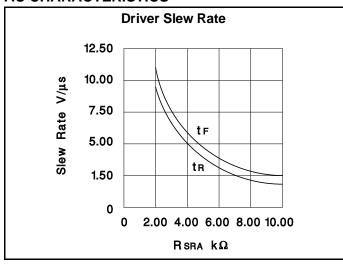
| PARAMETER                               | SYMBOL | TEST CONDITIONS     |     | TYP | MAX | UNITS |
|---|--------|---------------------|-----|-----|-----|-------|
| Output Slew Rate                        | tR     | RSRA = 2k           | 7.6 | 8.5 | 9.4 | V/μs  |
|   | tF     | RL = 450, CL = 50pF | 7.6 | 8.5 | 9.4 | V/μs  |
| Output Slew Rate                        | tR     | RSRA = 10k          | 1.5 | 1.7 | 1.9 | Vμs   |
|   | tF     | RL = 450, CL = 50pF | 1.5 | 1.7 | 1.9 | V/μs  |
| Propagation Output                      | tHz    | RSRA = 10k          |     | 8.0 | 2.0 | μs    |
| to High Impedance                       | tLz    | RL = 450, CL = 50pF |     | 0.5 | 2.0 | μs    |
| Propagation High<br>Impedance to Output | tzH    | RSRA = 10k          |     | 2.0 | 7.0 | ms    |
|   | tzL    | RL = 450, CL = 50pF |     | 1.0 | 7.0 | μs    |

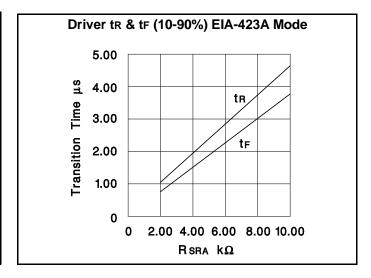
## AC PARAMETER TEST CIRCUIT AND WAVEFORMS





## **AC CHARACTERISTICS**





## APPLICATIONS Slew Rate Programming

Slew rate for the UC5172 is set up by a single external resistor connected between the SRA pin and ground. Slew rate adjustments can be approximated by using the following formula:

$$V/\mu s = \frac{20}{RSRA}$$
 (RSRA in k $\Omega$ )

The slew rate resistor can vary between 2k and  $10k\Omega$  which allows slew rates between 10 to  $2.2V/\mu s$ , respectively. The relationship between slew rate and RSRA is shown in the typical characteristics.

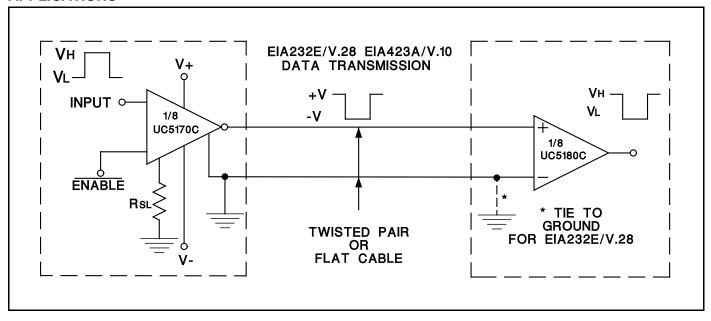
Waveshaping of the output lets the user control the level of interference (near-end crosstalk) that may be coupled to adjacent circuits in an interconnection. The recommended output characteristics for cable length and data rates can be found in EIA standard EIA-423A. Approximations of these standards are given by the following equations:

Max. Data Rate = 300/t (For data rates 1k to 100k bit/s)
Max. Cable Length (feet) = 100 x t (Max. length 4000 feet)

where t is the transition time from 10% to 90% of the output swing in microseconds. For data rates below 1k bit/s, t may be up to 300 microseconds.

The UC5172 has been used in applications up to 460KBPS.

#### **APPLICATIONS**



## **Specific Layout Notes**

The UC5172 layout must have bulk bypassing close to the device. Peak slew current is greater than 500mA when all eight drivers slew at once in the same direction. Some applications mount the UC5172 on a bulkhead or isolated plane for RFI/FCC/VDE reasons. If bulk bypassing is not used, the -10V supply may go above -8.5 volts, causing the slew rate control circuit to become unstable.

The UC5172 can have output oscillation at 100kHz if the +10V supply is applied before the -10V supply. This has been a problem in some terminal designs where the +10V was developed from the flyback, which can result in a 500ms difference in the application of the supplies at power up.

#### **General Layout Notes**

The drivers and receivers should be mounted close to the system common ground point, with the ground reference tied to the common point to reduce RFI/EMI.

Filter connectors or transzorbs should be used to reduce the RFI/EMI, protecting the system from static (ESD), and electrical overstress (EOS). A filter connector or capacitor will reduce the ESD pulse by 90% typically. A cable dragged across a carpet and connected to a system can easily be charged to over 25,000 volts. This is a metal to metal contact when the cable is connected to the system (no resistance), currents exceed 80 amps with less than a nanosecond rise time. A transzorb provides two functions, the device capacitance inherently acts as a filter capacitor, and the device clamps the ESD and EOS pulses which would pass through the capacitor and destroy the devices. The recommended transzorb for the UC5172 is P6KEIOCA.

\*Transzorb is a trademark of General Semiconductor Industries.

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